

2SD667(A)
Rev.F Mar.-2016

KF \$0) CD

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Silicon NPN transistor in a TO-92LM Plastic Package.

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2SD667(A)

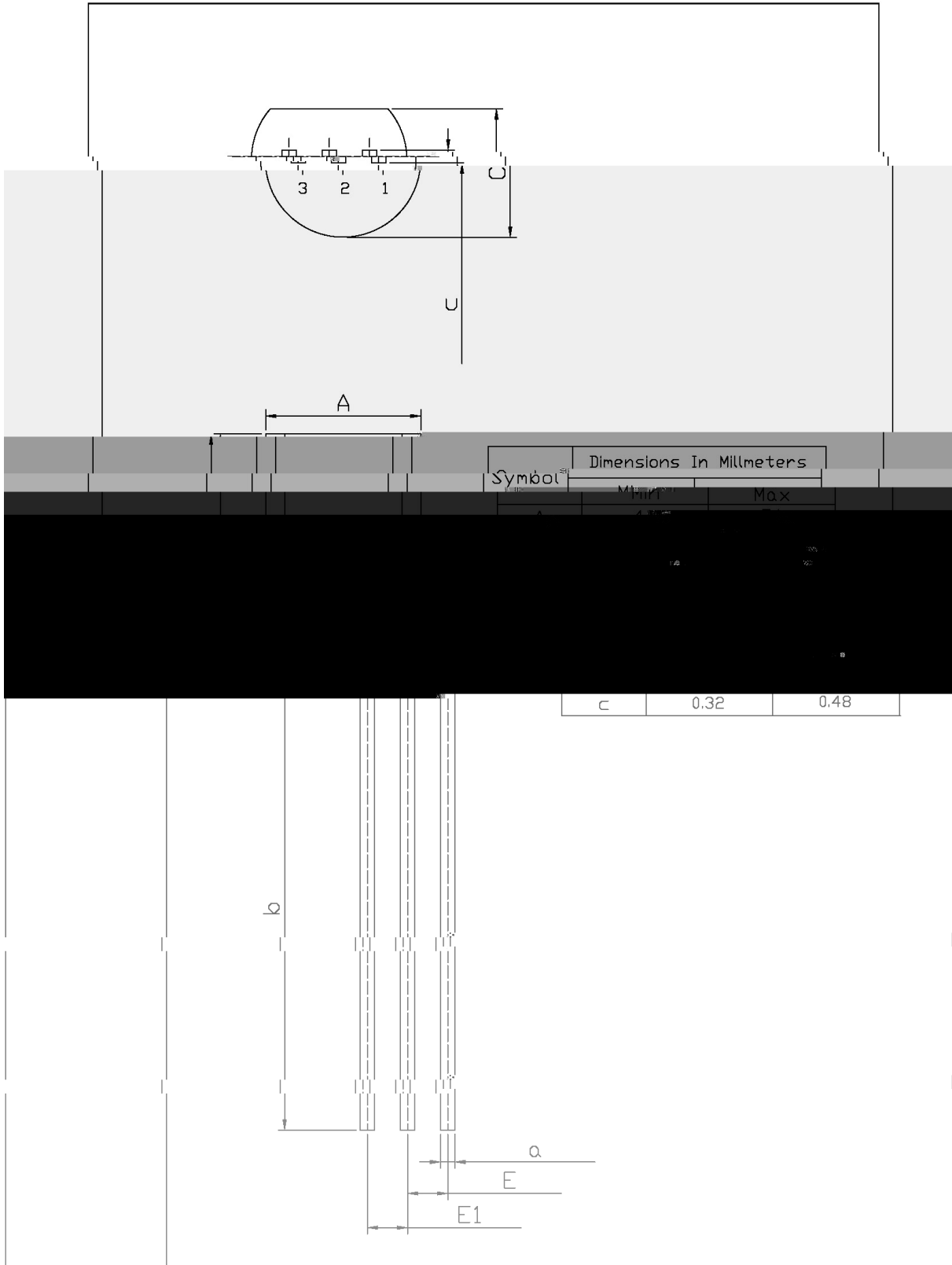
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Parameter	Symbol	Rating	Unit
Collector to Base Voltage			

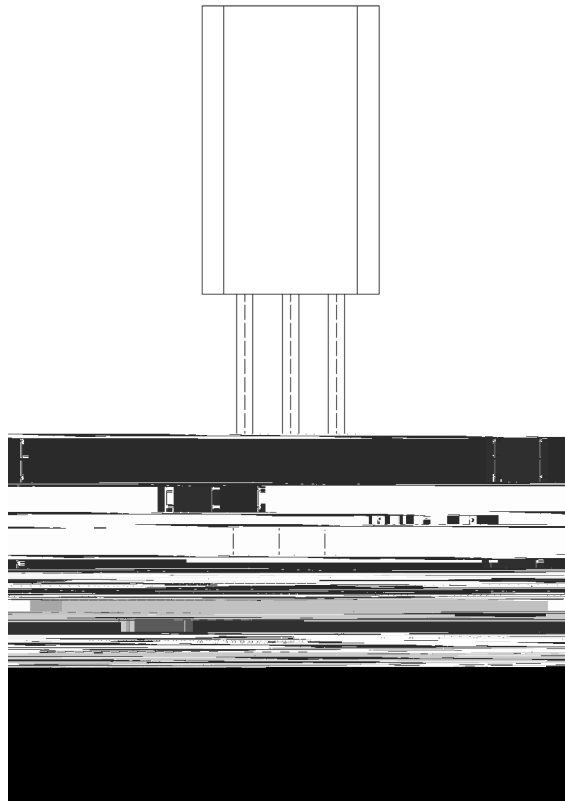
/ Package Dimensions

T0-92LM

Unit: mm

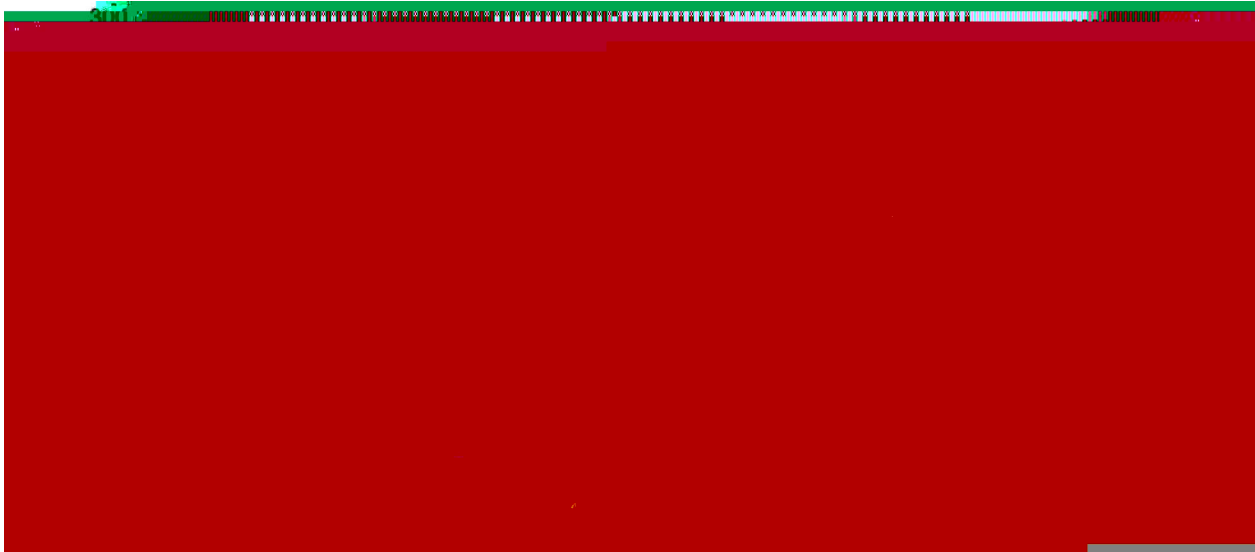


/ Marking Instructions



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() / Temperature Profile for Dip Soldering(Pb-Free)



				Note:
1	25	150	60 90sec;	1.Preheating:25~150 , Time:60~90sec.
2	255..5		5..0.5sec;	2.Peak Temp.:255..5 , Duration:5..0.5sec.
3		2	10 /sec.	3. Cooling Speed: 2~10 /sec.

/ Resistance to Soldering Heat Test Conditions

270..5 10..1 sec. Temp.:270±5 Time:10±1 sec

/ Packaging SPEC.

/ BULK

Package Type	Units	Dimension	(unit mm3)
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